

达林顿光耦 Darlington Photo Coupler

AT4NXX

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

www.aotesemi.com

概述 Description

AT4NXX是一款由 GaAs发光二极管和达林顿晶体管组成的光电耦合器。可以在保持驱动电路和负载电路之间的高度隔离的同时实现开关，具有使用寿命长、速度快等优点能让它替代常规继电器。

The AT4NXX is a photoelectric coupler composed of GaAs light-emitting diode and Darlington transistor. The switch can be realized while maintaining the high isolation between the drive circuit and the load circuit, which has the advantages of long service life and fast speed, allowing it to replace the conventional relay.

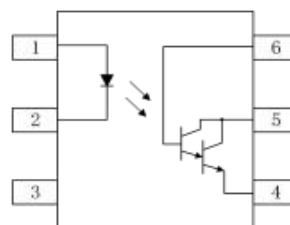
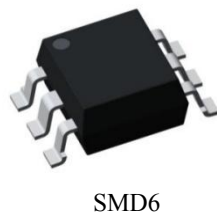
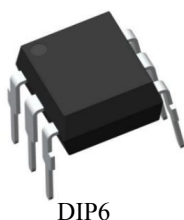
特性 Features

- 电流转换比(CTR)范围: $CTR \geq 500\%$
Current to current ratio range: $CTR \geq 500\%$
- 输入-输出隔离电压: $V_{iso} = 5000 \text{ V rms}$
Input-output isolation voltage: $V_{iso} = 5000 \text{ Vrms}$
- 输入-输出隔离电阻: 典型值 $R_{iso} = 10^{11} \Omega$
Input-output isolation resistance: Typical $R_{iso} = 10^{11} \Omega$
- 符合安规标准: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Meet Safety standard: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

应用 Applications

- 开关电源
Switching power supply
- 工业控制, 测量仪器
Industrial control, measuring instruments
- 可编程控制器
Programmable controller
- 家用电器
Household appliances

封装和原理图 Package and Schematic Diagram



Pin Configuration

1. Anode
2. Cathode
3. NC
4. Emitter
5. Collector
6. Base



产品型号命名规则 Order Code

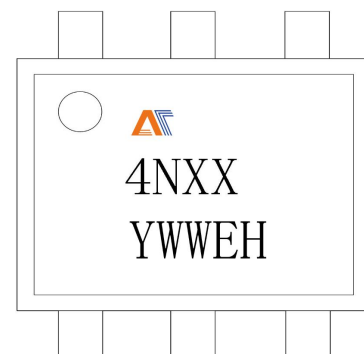
AT 4NXX - UN Y - W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特AOTE)
- ② 产品系列 Product Series (XX: 29, 30,31,32,33)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (D: DIP ; S: SMD)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range or None)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
 “” denotes LOGO
- 印字中的 “XX” 代表产品分档：29、30、31、32、33
 “XX” denotes the classification：29、30、31、32、33
- 印字中 “Y” 代表年份；A(2018),B(2019),C(2020).....
 “Y” denotes YEAR：A(2018), B(2019), C(2020).....
- 印字中 “WW” 代表周号
 “WW” denotes Week’ s number
- 印字中 “E” 代表内部代码
 “E” denotes Internal code
- 印字中的 “H” 代表无卤
 “H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

| 项目 Item | 符号 Symbol | 数值 Value | 单位 Unit | 备注 Remark |
|---------------------------------------|--------------|-------------|------------|--|
| 爬电距离 Creepage Distance | L | >7.6 | mm | 从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body |
| 电气间隙 Clearance Distance | L | >7.6 | mm | 从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air |
| 绝缘距离 Insulation Thickness | DTI | > 0.4 | mm | 发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector |
| 峰值隔离电压 Peak Isolation Voltage | V_{IORM} | 1500 | V_{peak} | DIN/EN/IEC EN60747-5-5 |
| 瞬态隔离电压 Transient isolation voltage | V_{IOTM} | 7000 | V_{peak} | DIN/EN/IEC EN60747-5-5 |
| 隔离电压 Isolation Voltage | Viso | >5000 | V_{rms} | For 1 min |

极限参数 Absolute Maximum Ratings (Ta = 25°C)

| | 参数 Parameter | 符号 Symbol | 额定值 Rating | 单位 Unit |
|--|--|--------------|---------------|------------|
| 发射端 Input | 正向电流 Forward Current | I_F | 60 | mA |
| | 峰值正向电流(1us, 脉冲) Peak forward current (1us, pulse) | I_{FP} | 1 | A |
| | 反向电压 Reverse Voltage | V_R | 3 | V |
| | 功耗 Power Dissipation | P_D | 100 | mW |
| 接收端 output | 集电极功耗 Collector Power Dissipation | P_C | 150 | mW |
| | 集电极电流 Collector Current | I_C | 100 | mA |
| | 集电极-基极电压 Collector-Base voltage | V_{CBO} | 50 | V |
| | 发电极-基极电压 Emitter-Base voltage | V_{EBO} | 8 | V |
| | 集电极-发射极电压 Collector-Emitter voltage | V_{CEO} | 30 | V |
| | 发射极-集电极电压 Emitter-Collector voltage | V_{ECO} | 5 | V |
| 总功耗 Total Power Dissipation | P_{tot} | 250 | mW | |
| 输入输出瞬态耐受电压 Input-output isolation voltage | V_{iso} | 5000 | V_{rms} | |

| 参数 Parameter | 符号 Symbol | 额定值 Rating | 单位 Unit |
|-------------------------------|--------------|---------------|------------|
| 工作温度 Operating Temperature | T_{opr} | -55 ~ +100 | °C |
| 存储温度 Storage Temperature | T_{stg} | -55 ~ +125 | °C |
| 焊接温度 Soldering Temperature | T_{sol} | 260 | °C |

产品特性参数 Electro-optical Characteristics (Ta = 25°C)

| 参数 Parameter | | 符号 Symbol | 条件 Condition | 最小 Min. | 典型 Typ. | 最大 Max. | 单位 Unit |
|-------------------------------------|---|---------------|--|------------|------------|------------|------------|
| 发射端 Input | 正向电压 Forward Voltage | V_F | $I_F = 10mA$ | - | 1.3 | 1.5 | V |
| | 反向电流 Reverse Current | I_R | $V_R = 3V$ | - | - | 10 | μA |
| | 输入电容 Terminal Capacitance | C_t | $V=0, F=1KHz$ | - | 50 | - | pF |
| 接收端 Output | 集电极暗电流 Collector Dark Current | I_{CEO} | $V_{CE} = 10V$ | - | - | 100 | nA |
| | 集电极-基极击穿电压 Collector-Base Breakdown Voltage | BV_{CBO} | $I_B = 0.1mA, I_F = 0$ | 50 | - | - | V |
| | 集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage | BV_{CEO} | $I_C = 0.1mA, I_F = 0$ | 40 | - | - | V |
| | 发射极-集电极击穿电压 Emitter-Collector Breakdown Voltage | BV_{ECO} | $I_E = 0.1mA, I_F = 0$ | 7 | - | - | V |
| 传输特性 Transfer Characteristics | 电流传输比 Current Transfer Ratio | 4N31 | $I_F = 10mA, V_{CE} = 10V$ | 50 | - | - | % |
| | | 4N29、4N30 | | 100 | - | - | % |
| | | 4N32、4N33 | | 500 | - | - | % |
| | 集电极-发射极饱和压降 Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_F = 8mA, I_C = 2mA$ | - | - | 1 | V |
| | 隔离电阻 Isolation Resistance | R_{ISO} | DC=500V 40~60%R.H. | - | 10^{11} | - | Ω |
| | 隔离电容 Isolation capacitance | C_{ISO} | $V=0, f=1MHz$ | - | 0.8 | - | pF |
| | 开启时间 Turn-on Time | T_{on} | $V_{CE} = 10V,$ $I_C = 50mA, R_L = 100\Omega$ | - | - | 5 | μs |
| | 关断时间 Turn-off Time | T_{off} | | - | - | 100 | μs |

 注*：电流传输比= $I_C/I_F \times 100\%$ 。

 Note*：CTR= $I_C/I_F \times 100\%$ 。

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Forward Current vs. Forward Voltage

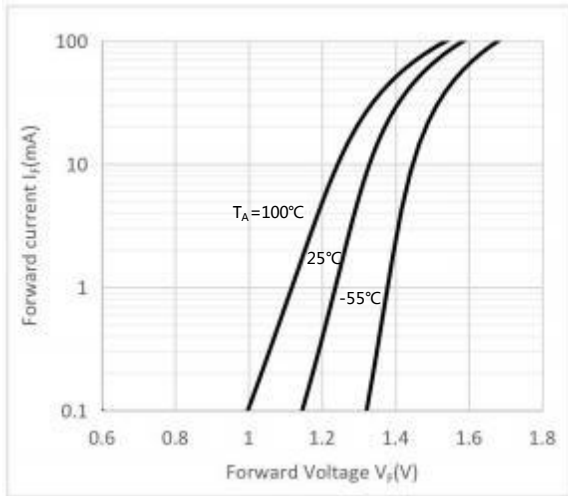


Fig.2 Current Transfer Ratio vs. Ambient Temperature

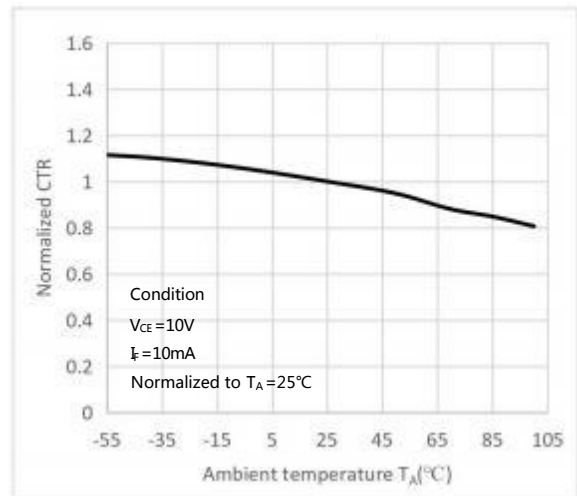


Fig.3 Normalized Current Transfer Ratio vs. Forward Current

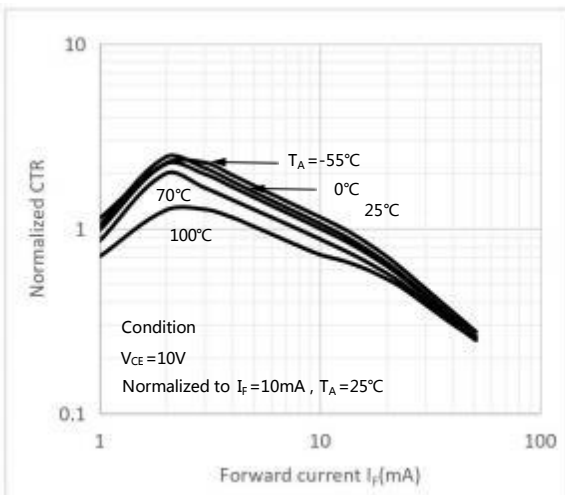


Fig.4 Collector Dark Current vs. Ambient Temperature

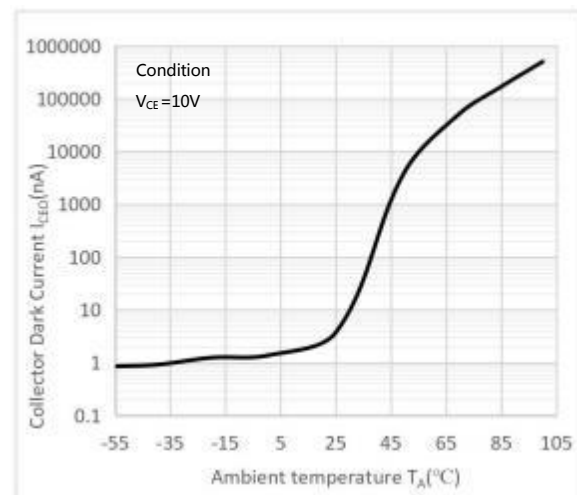


Fig 5. Turn-on Time vs Forward Current

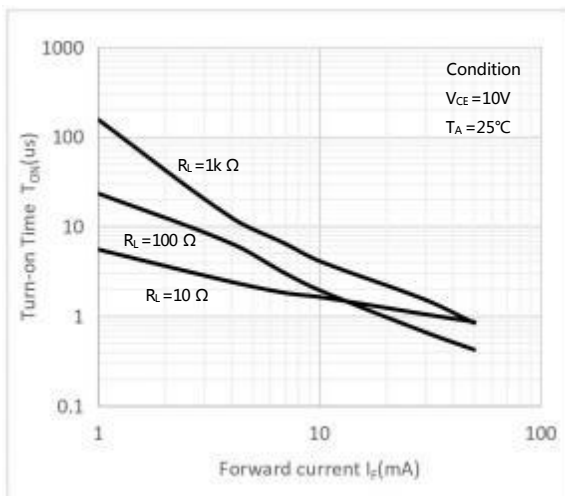
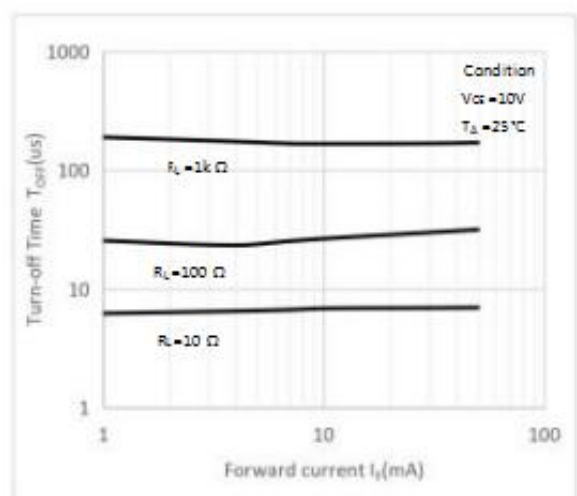
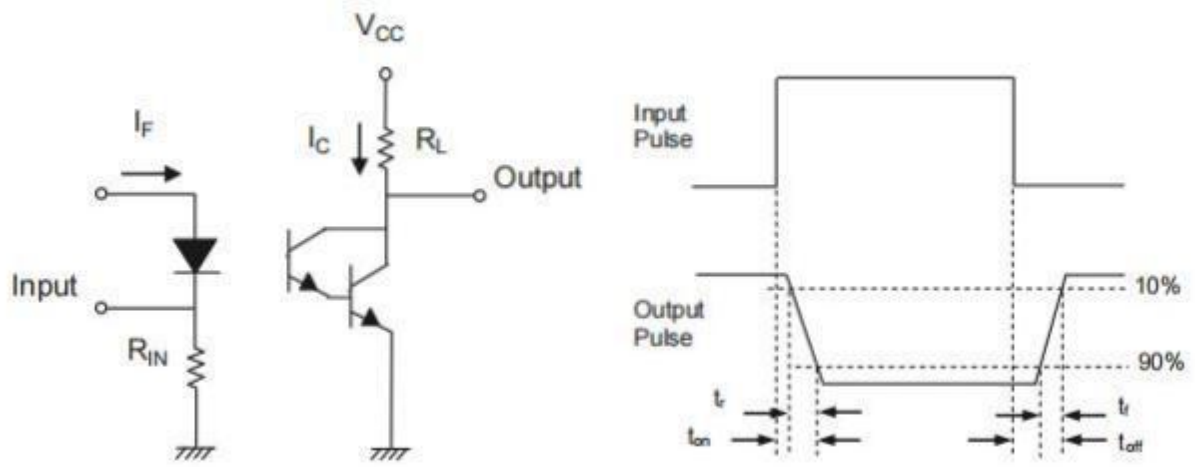


Fig 6. Turn-off Time vs Forward Current

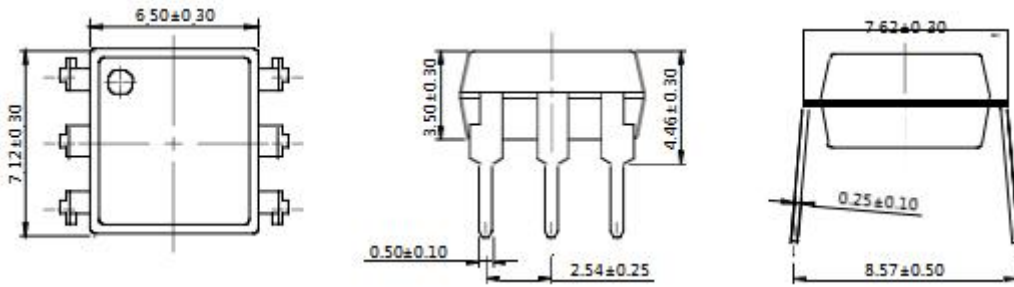


开关时间测试电路 Switching Time Test Circuit

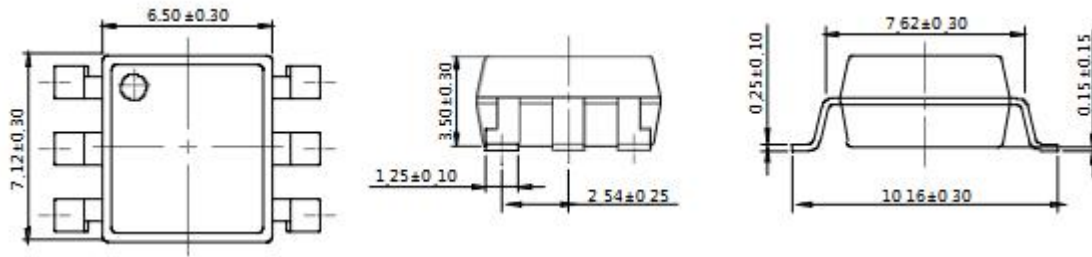


外形尺寸 Outline Dimensions

DIP6

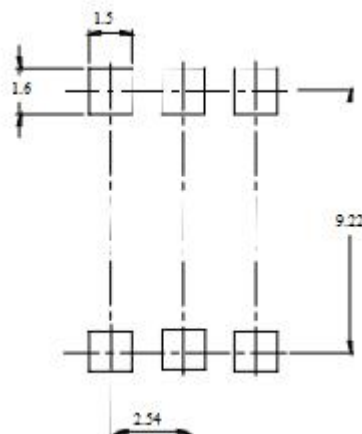


SMD6



单位 Unit: mm

建议焊盘布局 Recommended Pad Layout

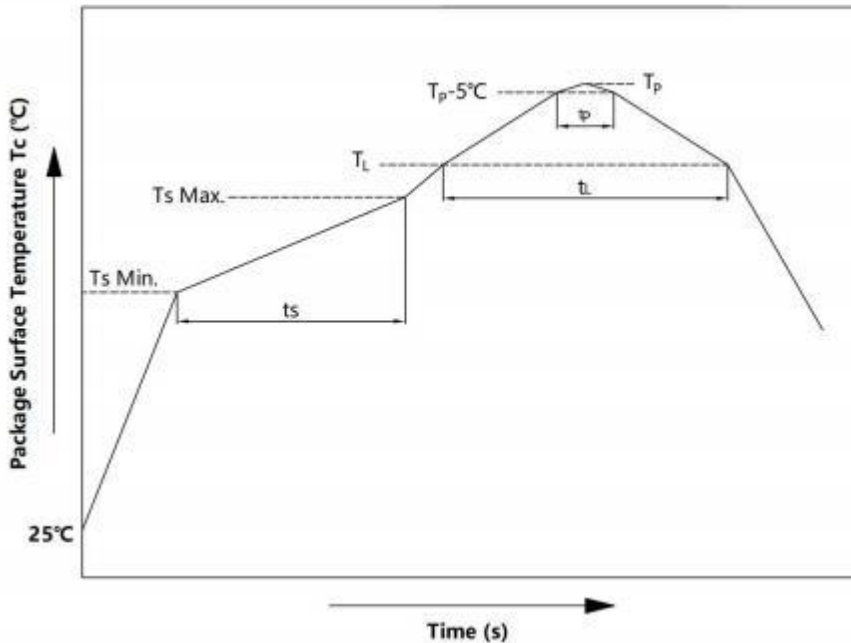


单位 Unit: mm

注：上图为产品正视图。

Note : The picture above is the front view of the product.

回流焊温度曲线图 Solder Reflow Profile



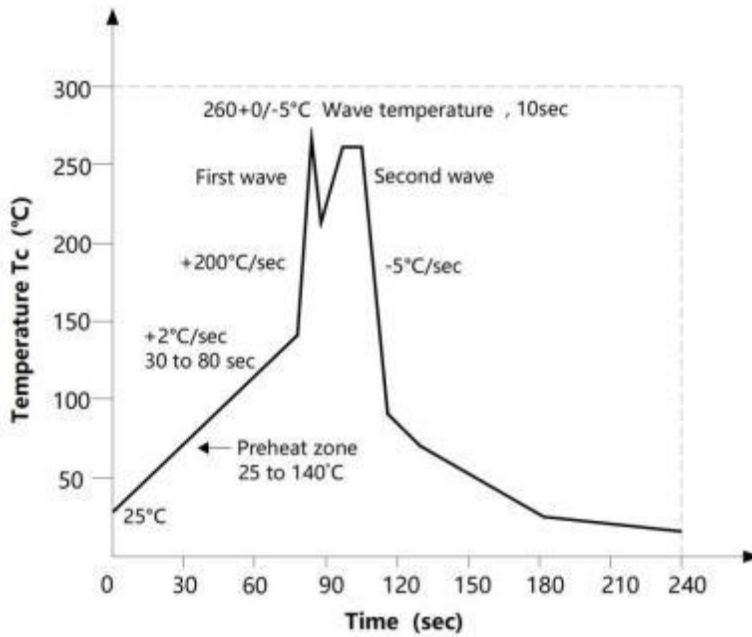
| 项目 Item | 符号 Symbol | 最小值 Min. | 最大值 Max. | 单位 Unit |
|---|--------------|-------------|-------------|--------------------|
| 预热温度 Preheat Temperature | T_s | 150 | 200 | $^\circ\text{C}$ |
| 预热时间 Preheat Time | t_s | 60 | 120 | s |
| 升温速率 Ramp-Up Rate (T_L to T_P) | - | - | 3 | $^\circ\text{C/s}$ |
| 液相线温度 Liquidus Temperature | T_L | 217 | | $^\circ\text{C}$ |
| 时间高于 T_L Time Above T_L | t_L | 60 | 150 | s |
| 峰值温度 Peak Temperature | T_P | - | 260 | $^\circ\text{C}$ |
| T_c 在 $(T_P - 5)$ 和 T_P 之间的时间 Time During Which T_c Is Between $(T_P - 5)$ and T_P | t_p | - | 30 | s |
| 降温速率 Ramp-down Rate (T_P to T_L) | - | - | 6 | $^\circ\text{C/s}$ |

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。
Manual soldering method Temperature: $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

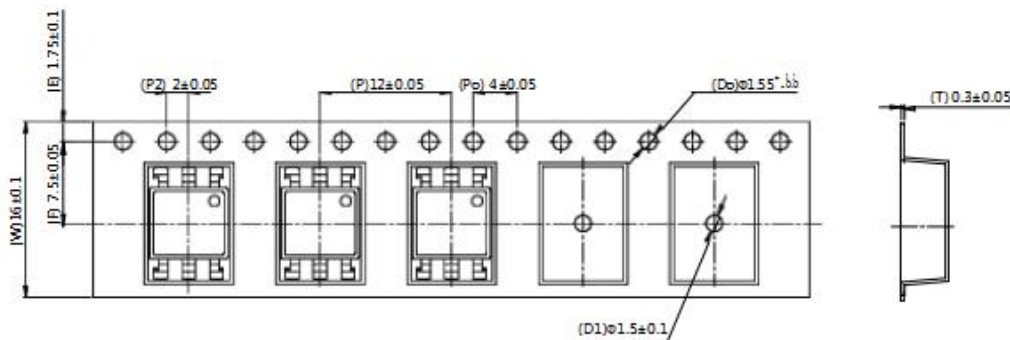
包装 Packing

■ 汇总表 Summary table

| 封装形式 | 包装方式 | 盘数量 | 盒数量 | 箱数量 | 静电袋规格 | 盒规格 | 箱(双瓦楞)规格 | 备注 |
|--------------|-----------------------|-------------------|------------------|---------------------|------------------------------|-------------------|----------------------|---|
| DIP6 | 管装 (500*12*11mm) | 65 只/管 | 50 管/盒 | 10 盒/箱 | 不适用 | 525*128*56mm | 535*275*300mm | 每管使用蓝白胶塞，方向须一致 |
| SMD6 | 卷盘 (φ330mm 蓝盘) | 1 千只/盘 | 2 盘/盒 | 10 盒/箱 | 450*390*0.1mm | 340*60*340mm | 620*360*365mm | 首尾端至少空 200 毫米 |
| Package Type | Packing Form | Quantity per Reel | Quantity per Box | Quantity per Carton | Antistatic Bag Specification | Box Specification | Carton Specification | Note |
| DIP6 | Tube (500*12*11mm) | 65 pcs/tube | 50 tubes/box | 10 boxes/ctn | Not applicable | 525*128*56mm | 535*275*300mm | Use blue and white rubber stoppers for each tube, with the same direction |
| SMD6 | Reel (φ330mm Blue) | 1k pcs/reel | 2 reels/box | 10 boxes /ctn | 450*390*0.1mm | 340*60*340mm | 620*360*365mm | Guard band 200mm min. |

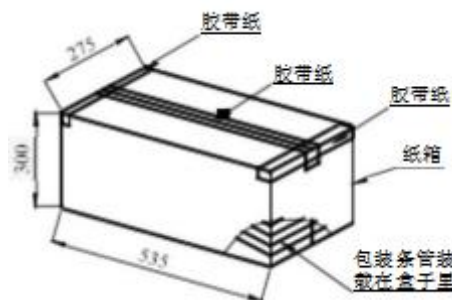
■ 编带包装 Tape & Reel

- 1) 每卷数量：1000 只。
Qty/reel : 1000 pcs.
- 2) 每箱数量：20000 只。
Qty/ctn : 20000 pcs.
- 3) 内包装：每盒 2 盘。
Inner packing : 2 reels/box.
- 4) 示意图 Schematic :



■ 管条包装 Tape & Tube

- 1) 每管数量：65 只。
Qty/Tube : 65 pcs.
- 2) 每箱数量：32500 只。
Qty/ctn : 32500 pcs.
- 3) 内包装：每盒 50 管。
Inner packing : 50 Tube/box.
- 4) 示意图 Schematic



单位/Unit : mm

注意 Attention

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